



Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, CA 90638

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SSR1645CTJ
SSR1645CAJ
SSR1645DJ

DESIGNER'S DATA SHEET

Part Number / Ordering Information ^{1/}

SSR1645 CT J UB TX

+ Screening ^{2/} — = Not Screened

TX = TX Level

TXV = TXV Level

S = S Level

+ Lead Bending: ^{3/}

— = Straight

UB = Up Bend

DB = Down Bend

+ Package: ^{3/}

J = TO-257

+ Configuration:

CT = Common Cathode

CA = Common Anode

D = Doubler

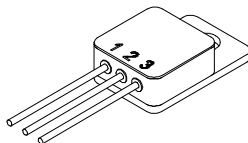
16A 45 V
SCHOTTKY
RECTIFIER

Features:

- PIV: 45Volts
- Low Reverse Leakage Current
- Low Forward Voltage Drop
- Guard Ring for Overload Protection
- Isolated Hermetically Sealed Package
- Custom Lead Forming Available
- Eutectic Die Attach
- 175°C Operating Temperature
- Ultrasonic Aluminum Wire Bonds
- TX, TXV, and S Level Screening Available

Maximum Ratings	Symbol	Value	Units
Peak Repetitive Reverse and DC Blocking Voltage	V_{RRM} V_{RSM} V_R	45	Volts
Average Rectified Forward Current ^{4/} (Resistive Load, 60 Hz Sine Wave, $T_A = 25^\circ\text{C}$)	I_O	16	Amps
Peak Surge Current ^{4/} (8.3 ms Pulse, Half Sine Wave, $T_A = 25^\circ\text{C}$)	I_{FSM}	250	Amps
Operating & Storage Temperature	T_{OP} & T_{STG}	-65 to +175	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JE}$	1.5	°C/W

TO-257 (J)



NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: SH0026B

DOC



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14830 Valley View Blvd * La Mirada, Ca 90638

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SSR1645CTJ

SSR1645CAJ

SSR1645DJ

Electrical Characteristic ^{5/}		Symbol	Min	Max	Units
Instantaneous Forward Voltage Drop (T _A = 25°C, 300µsec Pulse)	I _F = 5A	V _{F1}	—	0.54	V _{DC}
	I _F = 10A	V _{F2}	—	0.64	
	I _F = 16A	V _{F3}	—	0.76	
Instantaneous Forward Voltage Drop (T _A = -55°C, 300µsec Pulse)	I _F = 10A	V _{F4}	—	0.72	V _{DC}
Reverse Leakage Current (V _R = 45V, 300µs pulse min.)	T _A = 25°C	I _{R1}	—	200	µA
	T _C = 100°C	I _{R2}	—	15	mA
Junction Capacitance (V _R = 10V _{DC} , T _A = 25°C, f = 1MHz)		C _J	—	800	pF

NOTES:

1/ For Ordering Information, Price, and Availability Contact Factory.

2/ Screening per MIL-PRF-19500.

3/ For Package Outlines Contact Factory.

4/ Maximum Electrical Rating Shown for Centertap Configurations both Legs Tied Together.
For Doubler Configurations: I_O = 15A, I_{FSM} = 250A.

5/ All Electrical Characteristics per Leg @ 25°C, Unless Otherwise Specified.

Available Part Numbers:

SSR1645CTJ SSR1645CTJUB SSR1645CTJDB

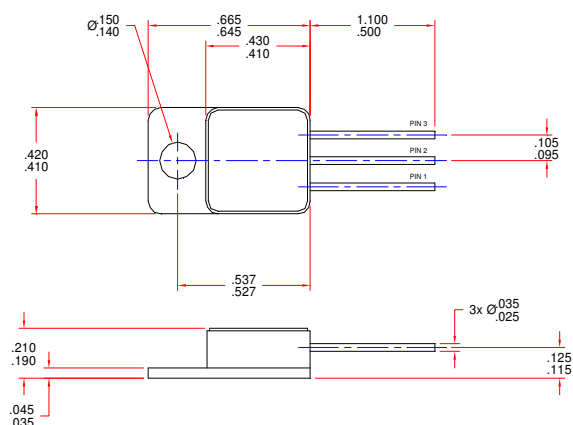
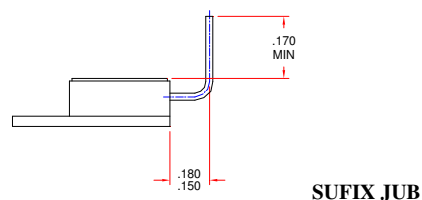
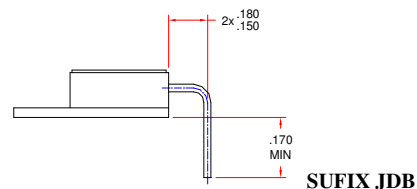
SSR1645CAJ SSR1645CAJUB SSR1645CAJDB

SSR1645DJ SSR1645DJUB SSR1645DJDB

PIN ASSIGNMENT

CONFIGURATION	Pin 1	Pin 2	Pin 3
Common Cathode (CT)	Anode	Cathode	Anode
Common Anode (CA)	Cathode	Anode	Cathode
Doubler (D)	Cathode	AC	Anode

CASE OUTLINE: TO257 (J)



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